



# BFR93A/BFR93AR/BFR93AW

Vishay Telefunken

## Silicon NPN Planar RF Transistor

Electrostatic sensitive device.  
Observe precautions for handling.

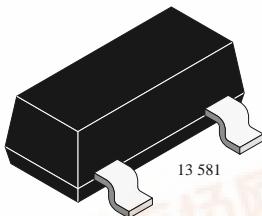
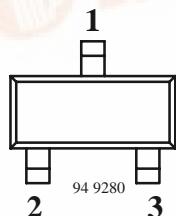


### Applications

Wide band amplifier up to GHz range.

### Features

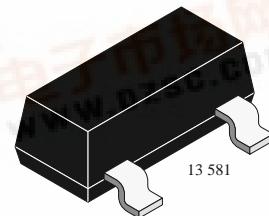
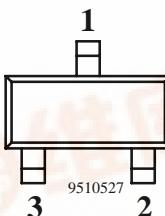
- High power gain
- High transition frequency
- Low noise figure



BFR93A Marking: +R2

Plastic case (SOT 23)

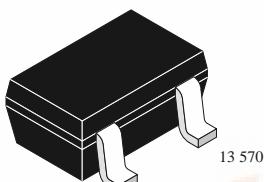
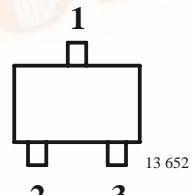
1 = Collector, 2 = Base, 3 = Emitter



BFR93AR Marking: +R5

Plastic case (SOT 23)

1 = Collector, 2 = Base, 3 = Emitter



BFR93AW Marking: WR2

Plastic case (SOT 323)

1 = Collector, 2 = Base, 3 = Emitter

# BFR93A/BFR93AR/BFR93AW



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## Absolute Maximum Ratings

$T_{amb} = 25^\circ C$ , unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Collector-base voltage		$V_{CBO}$	20	V
Collector-emitter voltage		$V_{CEO}$	12	V
Emitter-base voltage		$V_{EBO}$	2	V
Collector current		$I_C$	50	mA
Total power dissipation	$T_{amb} \leq 60^\circ C$	$P_{tot}$	200	mW
Junction temperature		$T_j$	150	$^\circ C$
Storage temperature range		$T_{stg}$	-65 to +150	$^\circ C$

## Maximum Thermal Resistance

$T_{amb} = 25^\circ C$ , unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on glass fibre printed board (25 x 20 x 1.5) mm <sup>3</sup> plated with 35 $\mu m$ Cu	$R_{thJA}$	450	K/W

## Electrical DC Characteristics

$T_{amb} = 25^\circ C$ , unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Collector cut-off current	$V_{CE} = 20 V$ , $V_{BE} = 0$	$I_{CES}$			100	$\mu A$
Collector-base cut-off current	$V_{CB} = 10 V$ , $I_E = 0$	$I_{CBO}$			100	nA
Emitter-base cut-off current	$V_{EB} = 2 V$ , $I_C = 0$	$I_{EBO}$			10	$\mu A$
Collector-emitter breakdown voltage	$I_C = 1 mA$ , $I_B = 0$	$V_{(BR)CEO}$	12			V
Collector-emitter saturation voltage	$I_C = 50 mA$ , $I_B = 5 mA$	$V_{CEsat}$		0.1	0.4	V
DC forward current transfer ratio	$V_{CE} = 5 V$ , $I_C = 30 mA$	$h_{FE}$	40	90	150	

## Electrical AC Characteristics

$T_{amb} = 25^\circ C$ , unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Transition frequency	$V_{CE} = 5 V$ , $I_C = 30 mA$ , $f = 500 MHz$	$f_T$		6		GHz
Collector-base capacitance	$V_{CB} = 10 V$ , $f = 1 MHz$	$C_{cb}$		0.45		pF
Collector-emitter capacitance	$V_{CE} = 5 V$ , $f = 1 MHz$	$C_{ce}$		0.2		pF
Emitter-base capacitance	$V_{EB} = 0.5 V$ , $f = 1 MHz$	$C_{eb}$		1.5		pF
Noise figure	$V_{CE} = 8 V$ , $Z_S = 50 \Omega$ , $f = 800 MHz$ , $I_C = 5 mA$	F		1.6		dB
	$V_{CE} = 8 V$ , $Z_S = 50 \Omega$ , $f = 800 MHz$ , $I_C = 25 mA$	F		2.1		dB
Power gain	$V_{CE} = 8 V$ , $I_C = 25 mA$ , $Z_S = 50 \Omega$ , $Z_L = Z_{Lopt}$ , $f = 800 MHz$	$G_{pe}$		14		dB
Linear output voltage – two tone intermodulation test	$V_{CE} = 8 V$ , $I_C = 25 mA$ , $d_{IM} = 60 dB$ , $f_1 = 806 MHz$ , $f_2 = 810 MHz$ , $Z_S = Z_L = 50 \Omega$	$V_1 = V_2$		260		mV
Third order intercept point	$V_{CE} = 8 V$ , $I_C = 25 mA$ , $f = 800 MHz$	$IP_3$		31		dBm



## Common Emitter S-Parameters

 $Z_0 = 50 \Omega$ ,  $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified

$V_{CE}/V$	$I_C/\text{mA}$	f/MHz	S11		S21		S12		S22	
			LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG
				deg		deg		deg		deg
8	5	100	0.811	-33.9	12.66	152.2	0.028	72.8	0.914	-15.0
		300	0.530	-83.4	8.32	117.3	0.058	57.8	0.661	-27.4
		500	0.370	-116.3	5.67	99.8	0.075	56.7	0.537	-26.9
		800	0.274	-149.7	3.77	85.0	0.099	59.8	0.487	-23.8
		1000	0.256	-165.5	3.11	77.8	0.117	61.8	0.485	-24.2
		1200	0.255	-178.6	2.67	71.1	0.135	62.6	0.481	-26.8
		1500	0.277	162.7	2.21	62.1	0.163	63.3	0.466	-31.3
		1800	0.294	146.0	1.91	54.0	0.194	63.3	0.455	-35.0
		2000	0.312	136.2	1.76	49.4	0.215	62.7	0.454	-38.4
		100	0.676	-44.9	19.22	142.3	0.025	69.9	0.832	-21.0
8	10	300	0.377	-97.1	10.24	108.0	0.050	62.8	0.539	-29.0
		500	0.259	-131.0	6.59	93.8	0.071	64.8	0.441	-25.0
		800	0.197	-164.2	4.26	81.6	0.102	66.9	0.415	-20.4
		1000	0.189	-178.0	3.48	75.4	0.124	67.2	0.423	-21.1
		1200	0.195	169.8	2.98	69.5	0.147	66.7	0.424	-24.2
		1500	0.222	155.6	2.46	61.4	0.179	65.4	0.409	-29.0
		1800	0.245	140.0	2.12	54.1	0.212	63.6	0.398	-32.6
		2000	0.263	131.3	1.95	49.9	0.235	62.0	0.397	-36.2
		100	0.597	-52.0	22.81	136.3	0.023	69.3	0.774	-23.9
		300	0.306	-105.2	10.94	103.8	0.047	66.5	0.484	-28.5
8	15	500	0.219	-139.3	6.91	91.3	0.070	68.4	0.405	-23.3
		800	0.172	-172.8	4.45	80.0	0.104	69.5	0.390	-18.3
		1000	0.165	174.6	3.62	74.3	0.128	69.0	0.401	-19.4
		1200	0.174	164.9	3.09	68.8	0.151	68.1	0.403	-22.7
		1500	0.201	152.9	2.54	61.0	0.185	66.0	0.388	-27.8
		1800	0.226	137.5	2.19	53.9	0.219	63.8	0.377	-31.4
		2000	0.245	128.5	2.01	49.7	0.243	61.8	0.375	-35.3

# BFR93A/BFR93AR/BFR93AW

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V <sub>CE</sub> /V	I <sub>C</sub> /mA	f/MHz	S11		S21		S12		S22	
			LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG
				deg		deg		deg		deg
8	20	100	0.540	-56.8	24.86	132.3	0.022	68.6	0.732	-25.5
		300	0.274	-110.3	11.22	101.5	0.046	68.6	0.455	-27.6
		500	0.199	-144.7	7.03	89.8	0.070	70.5	0.387	-21.9
		800	0.164	-177.3	4.49	79.2	0.105	70.9	0.380	-16.9
		1000	0.160	171.1	3.66	73.5	0.130	70.1	0.391	-18.2
		1200	0.166	162.3	3.13	68.2	0.153	68.6	0.393	-21.8
		1500	0.197	151.6	2.58	60.5	0.188	66.2	0.378	-27.1
		1800	0.223	135.8	2.21	53.7	0.222	63.8	0.367	-30.9
		2000	0.242	128.2	2.04	49.5	0.246	61.8	0.365	-34.7
	25	100	0.502	-61.1	26.06	129.3	0.021	68.7	0.702	-26.4
		300	0.254	-114.6	11.32	99.8	0.045	69.6	0.438	-26.5
		500	0.191	-148.9	7.05	88.8	0.070	71.5	0.378	-20.6
		800	0.162	178.0	4.51	78.5	0.106	71.5	0.374	-16.0
		1000	0.158	167.6	3.66	73.0	0.131	70.5	0.387	-17.5
		1200	0.163	159.3	3.13	67.6	0.154	69.0	0.389	-21.2
		1500	0.200	149.0	2.57	60.1	0.190	66.4	0.374	-26.6
		1800	0.220	134.7	2.21	53.2	0.224	63.8	0.364	-30.5
		2000	0.243	128.4	2.04	48.9	0.248	61.7	0.361	-34.4



# BFR93A/BFR93AR/BFR93AW

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**Typical Characteristics** ( $T_{amb} = 25^\circ C$  unless otherwise specified)

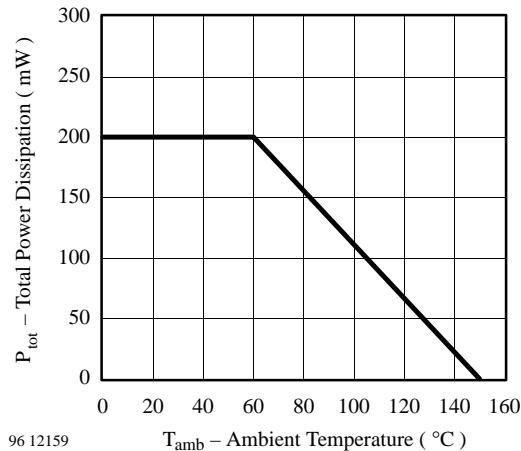


Figure 1. Total Power Dissipation vs.  
Ambient Temperature

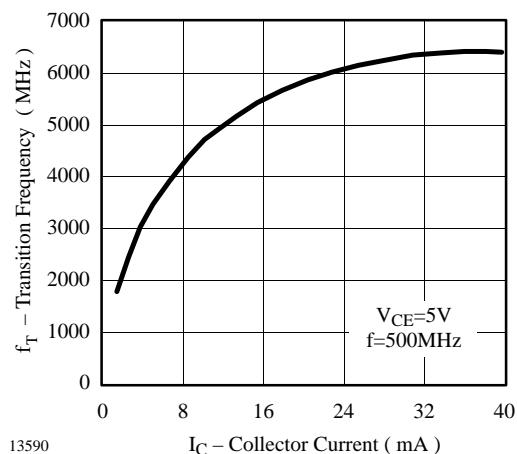


Figure 2. Transition Frequency vs. Collector Current

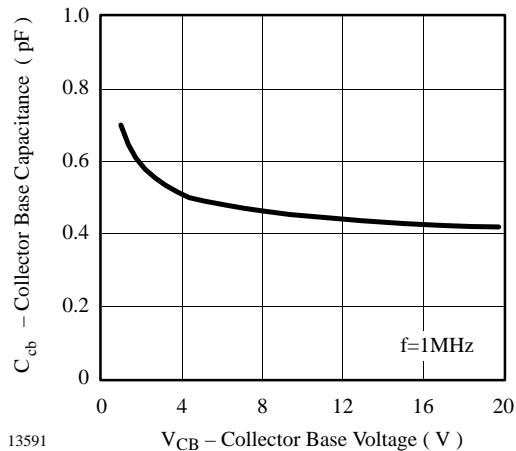


Figure 3. Collector Base Capacitance vs.  
Collector Base Voltage

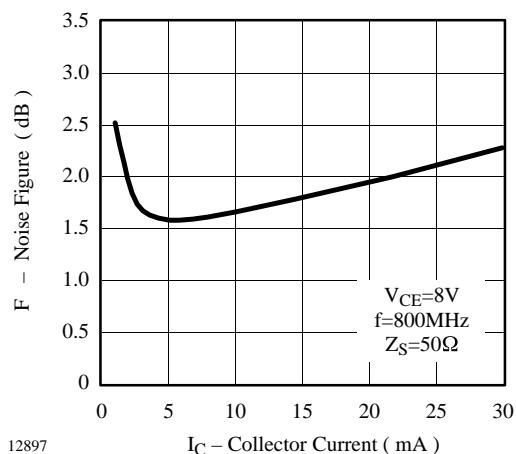


Figure 4. Noise Figure vs. Collector Current

# BFR93A/BFR93AR/BFR93AW

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$$V_{CE} = 8 \text{ V}, I_C = 25 \text{ mA}, Z_0 = 50 \Omega$$

$S_{11}$

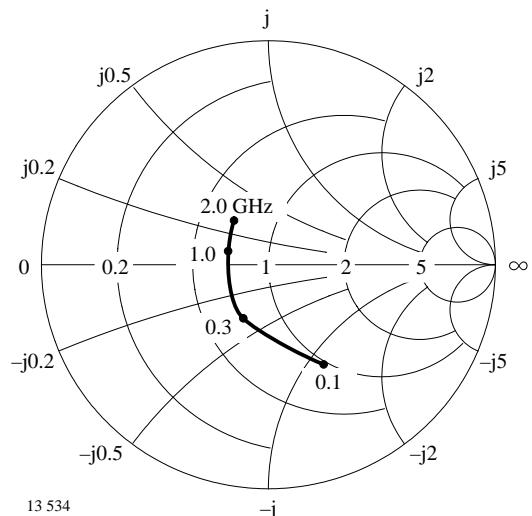


Figure 5. Input reflection coefficient

$S_{12}$

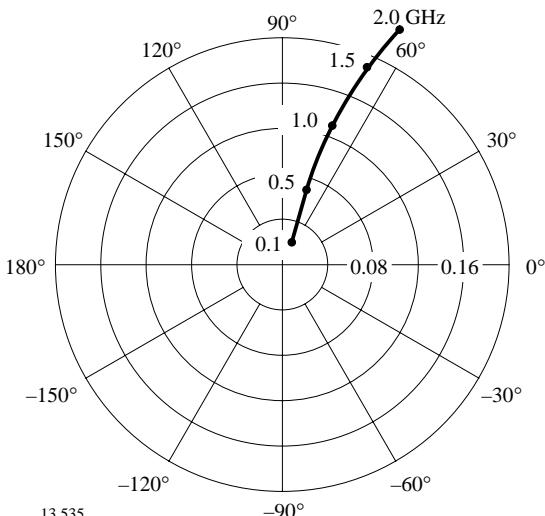


Figure 7. Reverse transmission coefficient

$S_{21}$

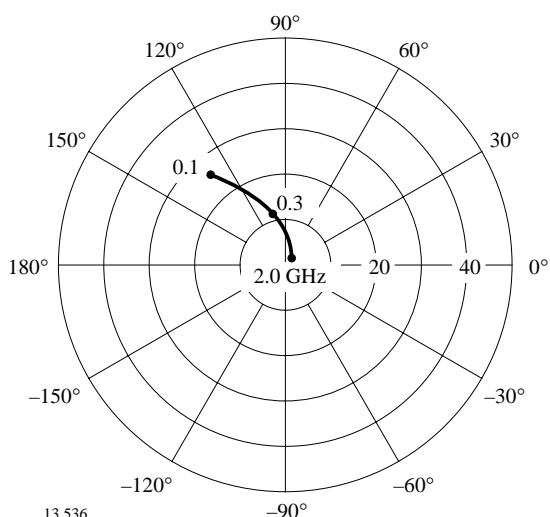


Figure 6. Forward transmission coefficient

$S_{22}$

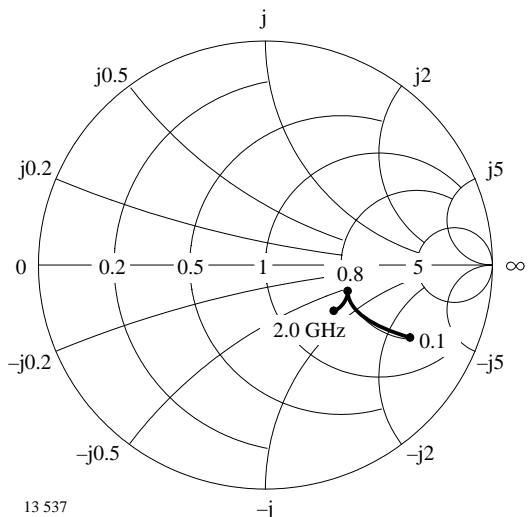


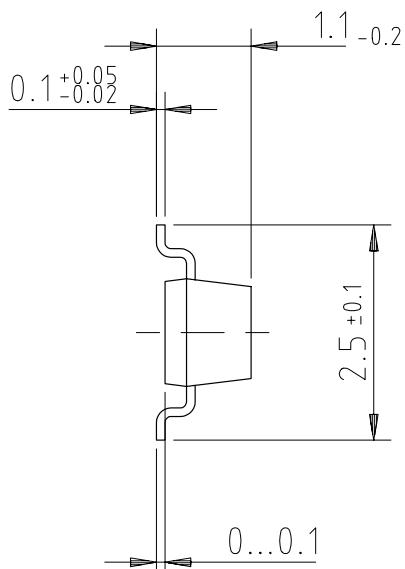
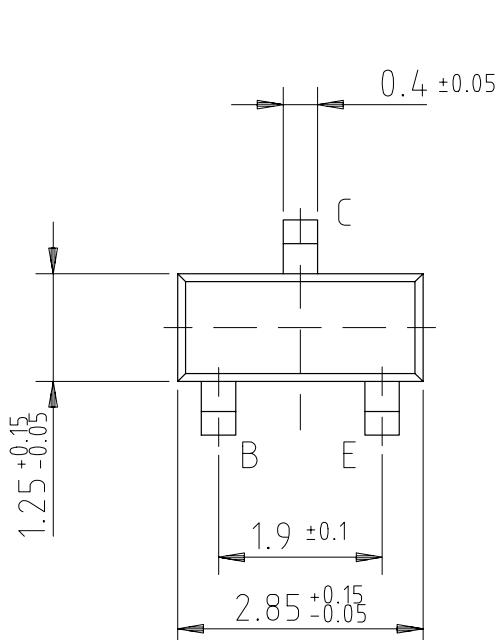
Figure 8. Output reflection coefficient



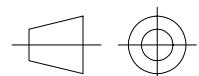
# BFR93A/BFR93AR/BFR93AW

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## Dimensions of BFR93A in mm

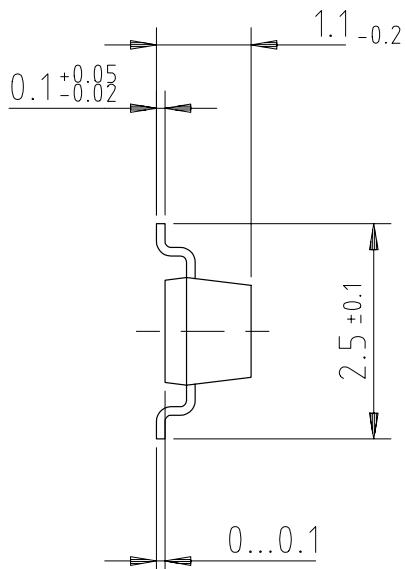
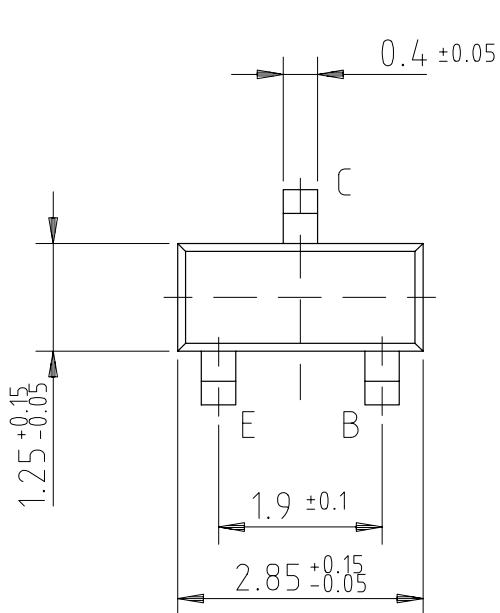


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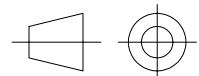


technical drawings  
according to DIN  
specifications

## Dimensions of BFR93AR in mm



95 11347



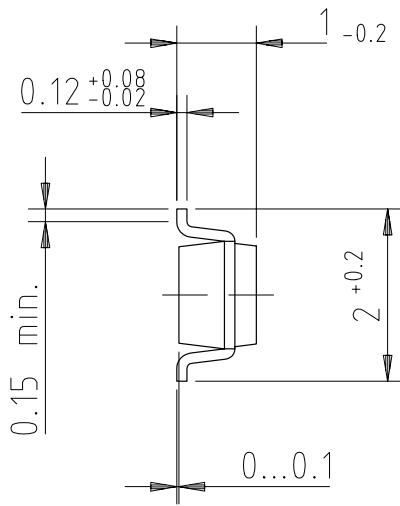
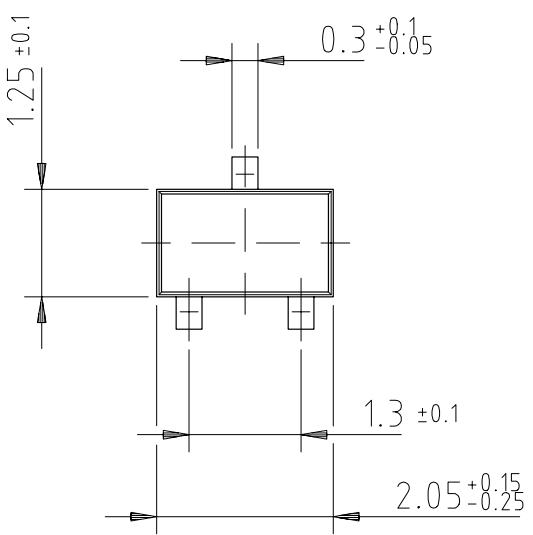
technical drawings  
according to DIN  
specifications

# BFR93A/BFR93AR/BFR93AW

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## Dimensions of BFR93AW in mm



96 12236

technical drawings  
according to DIN  
specifications



## Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany  
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423